Supporting Information

A two-dimensional hybrid with molybdenum disulfide nanocrystals strongly coupled on nitrogen-enriched graphene via mild temperature pyrolysis for high performance lithium storage

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Experimental Section

Materials and synthesis: Flake graphite was purchased from Aldrich. All other chemicals were purchased from Aladdin Reagent (Shanghai) and used without further purification.

Preparation of graphene oxide (GO): GO was synthesized from natural graphite flakes based on a modified Hummers method.³ A homogeneous GO aqueous dispersion (2.5 mg mL⁻¹) was then ready for use.

Preparation of protonated g-C₃N₄ (g-C₃N₄-H⁺): g-C₃N₄ was first obtained by thermal annealing of urea at 550 °C for 2h under air with a heating rate of 2 °C/min. Protonated g-C₃N₄ was prepared via sonication of g-C₃N₄ with HCl (37%) for 3 h at room temperature.

Synthesis of $MoS_2/NGg-C_3N_4$: GO aqueous dispersion (20 mL, 50mg) was first diluted in de-ionized (DI) water (200 mL) with addition of g-C₃N₄-H⁺ (100 mg) and sonicated for 1 h to obtain a flocculation of GO and g-C₃N₄-H⁺ (g-C₃N₄-H⁺/GO), which was then fed with Na₂MoO₄ • 2H₂O (300 mg) and stirred at 90 °C for 12 h. The following addition of Na₂S • 9H₂O (1.5g) and HCl (4 mL) immediately led to the formation of brownish precipitate (MoS₃/g-C₃N₄-H⁺/GO), which was collected by filtration, freeze-dried, and finally treated at 550 °C for 3h under N₂ with a heating rate of 5 °C/min to obtain $MoS_2/NGg-C_3N_4$. Moreover, another sample as $MoS_2/NGg-C_3N_4$ (10:100:50) could be obtained when 10 mg Na₂MoO₄ • 2H₂O was added with Na₂MoO₄ • 2H₂O:g-C₃N₄-H⁺:GO (10:100:50). As the optimized ratio, Na₂MoO₄ • 2H₂O:g-C₃N₄-H⁺:GO (300:100:50) was adopted to achieve appropriate MoS₂ loading and high content nitrogen doping in graphene. Synthesis of MoS_2/G : GO aqueous dispersion (20 mL, 50mg) was first diluted in DI water (200 mL) with subsequent addition of $Na_2MoO_4 \cdot 2H_2O$ (300 mg). The mixture was then stirred at 90 °C for 12 h. The following addition of $Na_2S \cdot 9H_2O$ (1.5g) and HCl (4 mL) immediately led to the formation of brownish precipitate (MoS_3/GO), which was collected by filtration, freeze-dried, and finally treated at 550 °C for 3h under N₂ with a heating rate of 5 °C/min to obtain MoS₂/G.

Synthesis of $MoS_2/NGurea$: MoS_3/GO obtained in above process was re-dispersed in DI water (50 mL) with an addition of urea (1 g) (10 times the mass of g-C₃N₄ in MoS_3/g -C₃N₄-H⁺/GO). Water was then evaporated via stirring the mixture at 80 °C. The resulting solid mixture was treated at 550 °C for 3h under N₂ with a heating rate of 5 °C/min to obtain $MoS_2/NGurea$.

Synthesis of MoS₂: Solution with Na₂MoO₄ • $2H_2O$ (300 mg) dispersed in DI water (200 mL) was stirred at 90 °C. Na₂S • $9H_2O$ (1.5g) and HCl (4 mL) were then added with brownish precipitate formed (MoS₃), which was collected by filtration, freeze-dried, and finally treated at 550 °C for 3h under N₂ with a heating rate of 5 °C/min to obtain MoS₂.

Characterizations: Zeta potential was acquired on ZS90 (Malvern Instruments Ltd, UK). XRD measurement was carried out on a D/max-2500 X-ray diffractometer (Rigaku Corporation, Japan) using Cu K_a radiation (λ =0.1542 nm). FTIR spectra were recorded using Spectrum 100 spectrometer (Perkin Elmer, Inc., USA). SEM images, EDX and elemental mapping were acquired using NOVA NanoSEM 230 microscope (FEI, USA). TEM images and SAED pattern were conducted on JEM-2100 microscope (JEOL Ltd., Japan). AFM images were taken on NanoNavi probe station in tapping mode (DI, USA). Nitrogen physisorption measurement was carried on Autosorb-iQA3200-4 sorption analyzer (Quantatech Co., USA). TGA curves were monitored on a Q5000IR apparatus (TA Instruments, USA). XPS experiment was carried out on AXIS Ultra DLD system from Kratos with Al Kα radiation as X-ray source for radiation. Raman measurement was conducted on an Invia/Reflrx Laser Micro-Raman spectrometer (Renishaw, England) excited by a laser beam of 532 nm.

Electrochemical Measurements:

Electrochemical tests of LIBs were performed under ambient temperature using twoelectrode 2032 coin-type cell. Pure lithium foil was used as the counter electrode. A microporous polypropylene membrane was used as the separator. The electrolyte consisting of a solution of 1 M LiPF₆ in ethylene carbonate (EC)/dimethyl carbonate (DMC) (1:1 by volume) was obtained from Ube Industries Ltd. The working electrodes were prepared by mixing the MoS₂ based materials (MoS₂/NGg-C₃N₄, MoS₂/NGurea, or MoS₂/G), carbon black (Super-P), and poly(vinyl difluoride) (PVDF) at a weight ratio of 8:1:1 and pasting the mixture on pure copper foil (99.6%). The electrode was dried at 60 °C for 12 h in a vacuum oven. The electrode was cut into $\Phi 11$ mm sheets and pressed. The amount of active materials loaded on the electrode was $\sim 1.5 \text{ mg} \cdot \text{cm}^{-2}$. The cells were assembled in an argon-filled glove box with the concentrations of moisture and oxygen below 1 ppm. CV tests were conducted on a CHI760 electrochemistry workstation at a scan rate of 0.1 mV/s. AC impedance spectroscopy was obtained by applying a sine wave with amplitude of 1.5 V over the frequency range from 100 kHz to 0.01 Hz. Galvanostatic charge/discharge measurements were conducted on a battery tester (Land CA2001A) at various current rates

in a potential range of 0.01-3.0 V vs. Li/Li⁺. The capacity was calculated based on the total mass of the materials.



Fig. S1 Photo images of $g-C_3N_4-H^+/GO$ flocculation, $MoS_3/g-C_3N_4-H^+/GO$ precipitate and the product of $MoS_2/NG_9-C_3N_4$.



Fig. S2 Zeta Potentials of (a) 0.25 mg/L GO aqueous solution, (b) 0.5 mg/L g-C₃N₄-H⁺ aqueous solution.



Fig. S3 TEM images of $g-C_3N_4-H^+/GO$.



Fig. S4 AFM images and corresponding height profiles of a) GO, and b) $g-C_3N_4-H^+/GO$.



Fig. S5 TEM images of $MoS_3/g-C_3N_4-H^+/GO$. MoO_4^{2-} ions can be integrated on the surface of $g-C_3N_4-H^+$ via ionic interactions to form MoS_3 nanoparticles by its precipitation with S^{2-} in acid environment.



Fig. S6 SEM images of $MoS_2/NG_{g-C_3N_4}$.



Fig. S7 TEM images of $MoS_2/NG_{g-C_3N_4}$.



Fig. S8 HRTEM images of $MoS_2/NG_{g-C_3N_4}$ with uniform (002) d-spacing of 0.66 nm.



Fig. S9 (a) TEM image of MoS_3/GO , MoO_4^{2-} ions can also be incorporated on GO, but via interactions between oxygen-containing groups on GO and the high valence Mo center;¹ (b) TEM, (c), and (d) HRTEM images of MoS_2/G with irregular (002) d-spacings.



Fig. S10 (a) TEM, (b-d) HRTEM images of MoS₂/NGurea with irregular (002) d-spacings.



Fig. S11 TEM images of (a) MoS_3 ; (b) bare MoS_2 with (002) d-spacing of 0.62 nm.



Fig. S12 Pore size distribution of MoS_2/NG_3N_4 according to DFT method. The pores are in the mesoporous range.



Fig. S13 TGA curves of MoS₃, g-C₃N₄-H⁺/GO, MoS₃/g-C₃N₄-H⁺/GO under N₂ at a heating rate of 5 °C/min.



Fig. S14 XRD pattern of the resulting material after thermal treatment of $MoS_3/g-C_3N_4-H^+/GO$ at 400 °C for 3 hours under N_2 .



Fig. S15 FTIR spectra of $g-C_3N_4-H^+/GO$, $g-C_3N_4/G$, $MoS_2/NG_g-C_3N_4$ and pure MoS_2 . $g-C_3N_4-H^+/GO$ displays typical CN heterocycle stretches in 1200-1680 cm⁻¹ and s-triazine vibration at 800 cm⁻¹ for $g-C_3N_4$. These features are maintained for $g-C_3N_4/G$, which is obtained by treatment of $g-C_3N_4-H^+/GO$ at 550 °C for 3h in N_2 .² In contrast, after treatment of $MoS_3/g-C_3N_4-H^+/GO$ at 550 °C, the $g-C_3N_4$ features are absent for $MoS_2/NG_g-C_3N_4$ with other arised peaks for MoS_2 and 1600 cm⁻¹ peak for C=N in graphene,³ confirming the complete decomposition of $g-C_3N_4-H^+$.



Fig. S16 TGA of MoS₂/NGg-C₃N₄ under air at a heating rate of 5 °C /min.



Fig. S17 a) TGA curves of $g-C_3N_4-H^+/GO$, $MoS_3/g-C_3N_4-H^+/GO$ (10:100:50), $MoS_3/g-C_3N_4-H^+/GO$ (300:100:50) under N_2 at a heating rate of 5 °C/min; b) FTIR spectra of $g-C_3N_4$, $MoS_2/NG_9-C_3N_4$ (10:100:50) and pure MoS_2 ; Core-level XPS spectra of c) C 1s; d) N 1s and Mo 2p for $MoS_2/NG_9-C_3N_4$ (10:100:50). TGA of $MoS_3/g-C_3N_4-H^+/GO$ (10:100:50) also shows promoted decomposition of $g-C_3N_4-H^+$ at 500-600 °C. FTIR functionalities of $g-C_3N_4$ are also in absence for $MoS_2/NG_9-C_3N_4$ (10:100:50). These results show that complete $g-C_3N_4-H^+$ decomposition can also be promoted by a small amount of MoS_3 in the precursor and successfully doped nitrogen into graphene.



Fig. S18 XPS (a) survey spectra; core-level spectra of (b) C 1s; (c) S 2p for MoS₂/NGg-C₃N₄.



Fig. S19 Core-level XPS spectra of (a) C 1s; (b) N 1s and Mo 2p; (c) Mo 3d and S 2s; (d) S 2p for MoS₂/NGurea.



Fig. S20 Core-level XPS spectra of (a) C 1s; (b) Mo 3d and S 2s; (c) S 2p for MoS₂/G.

Table S1. Nitrogen contents and fractions of the N configurations for $MoS_2/NGg-C_3N_4$ and $MoS_2/NGurea$ in this work, and typical literature reported N-doped graphene.

| Samples | Precursors | T | N/CN | Graphitic N | Pyrrolic N | Pyridinic N | Oxidized N |
|---|---|---------|-----------|-------------|------------|-------------|------------|
| MoS ₂ /NGg-C ₃ N ₄ | GO(50mg) | 550°C | 13 at.% | 30% | 15% | 55% | |
| | g-C ₃ N ₄ (100mg) | | | | | | |
| | NaMoO ₄ (300mg) | | | | | | |
| MoS ₂ /NGurea | GO(50mg) | 550°C | 12 at.% | 5% | 19% | 76% | |
| | urea(1 g) | | | | | | |
| | NaMoO ₄ (300mg) | | | | | | |
| NG ⁴ | GO:melamine | 800°C * | 6.6 at.% | 28.59% | 8.25% | 52.13% | 11.03% |
| | (1:5) | | | | | | |
| NG ⁵ | GO(50mg) | 800°C * | 7.86 at.% | 24% | 21.2% | 44.4% | 10.5% |
| | urea(250 mg) | | | | | | |

*It can be seen large fraction of graphitic N formation generally need high temperature above 800°C with less N content (< 10 at.%).



Fig. S21 a,b) SEM images of $MoS_2/NG_{g-C_3N_4}$ electrode on copper foil after 200 charge and discharge cycles. c,d) TEM images of $MoS_2/NG_{g-C_3N_4}$ after 200 charge/discharge cycles with well dispersed Mo species.⁶



Fig. S22 a,b) SEM images of MoS_2/G electrode on copper foil after 200 charge and discharge cycles. c,d) TEM images of MoS_2/G after 200 charge/discharge cycles.

Table S2. MoS_2 based hybrids (with C or graphene) prepared in this work and the reported literatures and their cycling and rate performances as anode in LIBs

| Samplas | Methods | Cycling | Discharge capacities (mAh g ⁻¹) | | |
|------------------------------------|--|--|---|------|--------|
| Sumples | | | 0.1 A/g | 1A/g | 10 A/g |
| MoS2/NGg-C3N4 in this work | MoS ₃ /g-C ₃ N ₄ -H ⁺ /GO treated at 550 °C | 1450 mAh g ⁻¹ at 0.1 A/g for 200 cycles | 1310 | 1200 | 830 |
| M0S2/NGurea | MoS ₃ /GO and urea treated at 550 $^{\circ}C$ | 800 mAh g ⁻ ¹ at 0.1 A/g for 200 cycles | 840 | 620 | 330 |
| MoS2/G | MoS ₃ /GO treated at 550 °C | 405 mAh g ⁻ ¹ at 0.1 A/g after 200 cycles | 820 | 500 | 160 |
| MoS ₂ /N-G ¹ | N-G prepared at 1050 °C , NaMoO4 and L- cysteine, hydrothermal at | 1285 mAh g ⁻¹ at 0.1 A/g after 50 | 1200 | 850 | |

| | 180°C, finally 800 °C in Ar | | | | |
|--|---|--|------|------|-----|
| PEO/MoS ₂ /Graphene ⁶ | Exfoliation and restacking | 1000 mAh g ⁻¹ at 0.05 A/g after 180 cycles | 900 | 500 | 300 |
| 3D MoS ₂ - graphene ⁷ | Exfoliation of MoS ₂ and hydrothermal with GO at 180°C | 1220 mAh g ⁻¹ at 74 mAh g ⁻¹ for 30 cycles; 711 mAh g ⁻¹ at 1860 mA g ⁻¹ | | | |
| MoS ₂ /CCG ⁸ | Exfoliation and restacking | 750 mAh g ⁻ ¹ at 0.1 A/g after 50 cycles | 957 | 470 | |
| MoS ₂ /3DGN ⁹ | CVD | 877 mAh g ⁻ ¹ at 0.1 A/g after 50 cycles | 849 | 597 | |
| MoS ₂ /G ¹⁰ | hydrothermal at 240 °C, finally 800 °C in Ar | 1187 mAh g ⁻¹ at 0.1 A/g after 100 cycles | 1187 | 900 | |
| MoS ₂ /GNS ¹¹ | hydrothermal at 240°C | 1290 mAh g ⁻¹ at 0.1 A/g after 50 cycles | 1290 | 1040 | |
| GL-MoS ₂ / G-CT01 ¹² | hydrothermal at 240°C, finally 800 °C in N ₂ | 1020 mAh g ⁻¹ at 0.1 A/g after 100 cycles | 1020 | 760 | |
| G/MoS2 ¹³ | hydrothermal at 200°C | 1023.7– 1234.8 mAh g ⁻¹ at 0.1 A/g during 100 cycles | 1200 | 848 | |
| MoS ₂ NS/graphene ¹⁴ | hydrothermal at 240°C | 875 mAh g ⁻¹ at 832 mAg ⁻¹ for 50 cycles; 709 mAh g ⁻ | | | |

| | | ¹ at 8320 | | | |
|--|---|---|---------|---------|------|
| | | mAg ⁻¹ | | | |
| SL-MoS2-GNS05 ¹⁵ | refluxed at 95 °C, 800 °C in N_2 | ¹ at 0.1 A/g after 100 cycles | 900 | 571 | |
| CNT@MoS2 NSs ¹⁶ | hydrothermal at 200°C, finally 800 °C in H ₂ /N ₂ | 698 mAh g ⁻ ¹ at 0.1 A/g after 60 cycles | 957 | 369 | |
| MoS2@CMK-3 ¹⁷ | hydrothermal at 200°C, 500 °C in H ₂ /N ₂ | 934 mAh g ⁻ ¹ at 0.4A/g after 150 cycles | 893 | 713 | <391 |
| MoS ₂ -carbon fiber ¹⁸ | Electrospinning, 450 °C in H ₂ /Ar (5 : 95 v/v), 800 °C under Ar | 1000*67% mAh g ⁻¹ at 1 A/g after 100 cycles | 986*67% | 637*67% | |
| MoS2-C nanotubes ¹⁹ | 400 °C under H ₂ S | 776 mAh g ⁻¹ at 0.2 A/g after 100 cycles | 1100 | 600 | |
| N-doped G-SnO ₂ ²⁰ | 800 °C under Ar | 910 mAh g ⁻¹ at 50 mA/g after 50 cycles | 900 | 683 | |
| SnO ₂ NC@N- RGO ²¹ | hydrothermal at 200°C and 120°C | 1346 mAh g ⁻¹ at 0.5 A/g after 500 cycles | | 994 | 631 |
| N-G/Fe ₃ O ₄ ²² | hydrothermal at 180°C , 500 °C under Ar | 1130 mAh g ⁻¹ at 0.1 A/g after 200 cycles | 1051 | | <648 |

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